Prepared	Product Specifications	Ref No.	A - 1
Checked	L	Total Page	12
Approved	AN7586	Page No.	1

Structure	Silicon Monolithic Bipolar IC	
Appearance	SIL-7 Pins Plastic Package (Power Type With Fin)	
Application	Low Frequency Amplifier	
Function	Mono 10W Audio Power Amplifier, with standby circuit and incorporating protection circuits	

A	Absolu	te Maximu	ım Ratings		
No.	Item	Symbol	Ratings	Unit	Note
1	Storage Temperature	Tstg	-55 ~ +150	° C	1
2	Operating Ambient Temperature	Topr	-25 ~ +75	° C	1
3	Operating Ambient Pressure	Popr	$\frac{1.013 \times 10^5 \pm 0.61 \times 10^5}{(1.0 \pm 0.6)}$	Pa (atm)	
4	Operating Constant Acceleration	Gopr	9,810 (1,000)	m / s ² (G)	
5	Operating Shock	Sopr	4,900 (500)	m / s ² (G)	
6	Power Supply Voltage	Vcc	35.0	V	
7	Power Supply Current	Icc	2.0	А	
8	Power Dissipation	Pd	18.7	W	2

Operating Supply Voltage Range	Vcc	10.0 V ~ 32.0 V	
--------------------------------	-----	-----------------	--

Note : 1) Except these items, all other measurements are taken at Ta = 25 °C.

2) Ta = 75 °C with infinite heat sink.

Eff. Date	Eff. Date	Eff. Date	Eff. Date
Lii: Dute	Ell: Date	Elli Dute	Ell. Dute
11-Feb-1999			
11-Feb-1999			

Prepared	Product Specifications	Ref No.	A-2
Checked	Ĩ	Total Page	12
Approved	AN7586	Page No.	2

A	Absolute Maximum Ratings				
No.	Item	Symbol	Ratings	Unit	Note
1	Pin Voltage (Pin 3)	V3	-0.3 ~ +3.0	V	

Note) For the above mentioned terminals do not apply a voltage or current that is outside the described range.

te Eff. Date Eff. Date Eff. Date

Prepared	Product Specifications	Ref No.	B - 1
Checked	ľ	Total Page	12
Approved	AN7586	Page No.	3

В	(Ambient t	Electrical Characteristics (Ambient temperature is 25°C±2°C unless otherwis							
No	It and	Course has 1	Test	Condition		Limit			Note
No.	Item	Symbol	Cct.	Condition	Min	Тур	Max	Unit	Note
1	Quiescent Current	Icq		Vin=0mV	-	30	60	mA	
2	Output End Noise Voltage	Vno		No input, Rg=10k	-	0.22	0.4	mV	2
3	Voltage Gain	Gv		Vin=57mV	32	34	36	dB	
4	Total Harmonic Distortion	THD		Vin=57mV	-	0.2	0.4	%	
5	Maximum Output Power	Ро		Vcc=26V, THD=10%	8.0	10.0	-	W	
6	Ripple Rejection Ratio	RR		Vr=1 Vrms, fr=120Hz,Rg=10k	45	55	-	dB	2
7	Stand-by On Voltage	Vstb-on		No input Icc ≤ 0.1mA	-	-	5.0	V	
8	Stand-by Off Voltage	Vstb-off		No input Icc ≥ 9.5mA	8.5	-	-	v	

Note : 1) f=1kHz, RL=8 Ω , Vcc=26V, unless otherwise stated

2) For this measurement, use the 20Hz~20kHz (12dB/OCT) filter.

Eff. Date	Eff. Date	Eff. Date	Eff. Date
11-Feb-1999			

Checked AN7586 Total Page 12 Approved AN7586 Total Page 12 Description of Test Circuits and Test Methods Test Circuit :	Prepared		D.	aduat Cra	aifiantiona	Ref No.	C - 1
Approved AN7586 Page No. 4 Description of Test Circuits and Test Methods Test Circuit :	Checked			ouuci spe	cifications		
Description of Test Circuits and Test Methods Test Circuit :				AN7	586		
$\begin{array}{c c c c c c c c c c c c c c c c c c c $			fircuits and T	Test Methods	3		
$\begin{array}{c c c c c c c c c c c c c c c c c c c $)	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			ľ	AN75	586		
For ' OPERATIONAL MODE ', connect STB to Vcc. Eff. Date Eff. Date Eff. Date Eff. Date		+ 	u m Rg	$ \begin{array}{c} + \\ + \\ 1000\mu \mathbf{Z} \\ + \\ \mathbf{Z} \\ \mathbf{Z} \\ \mathbf{Z} \\ \mathbf{Z} \\ \mathbf{U} \\ \mathbf{U}$		O_{STB}	
	Note	e: For ' OPE	RATIONAL N	IODE ', conne	ct STB to Vcc.		
	Eff. Date 11-Feb-1999	Eff. Date	Eff. Date	Eff. Date			





FMSC-PSDA-002-01

Prepared	Product Specifications	Ref No.	F
Checked	AN7586	Total Page	12
Approved	AIN/JOU	Page No.	7

(Structure Description)

Chip surface passivation	SiN,	PSG,	Others ()	1
Lead frame material	Fe group,	Cu group,	Others ()	2,6
Inner lead surface process	Ag plating,	Au plating,	Others ()	2
Outer lead surface process	Solder plating,	Solder dip,	Others ()	6
Chip mounting method	Ag paste,	Au-Si alloy, Solder,	Others ()	3
Wire bonding method	Thermalsonic be	onding,	Others ()	4
Wire material	Au,	Diameter 38 µm	Others ()	4
Mold material	Epoxy,		Others ()	5
Molding method	Transfer mold,	Multiplunger mold,	Others ()	5
Heat Fin Material	Fe group,	Cu group,	Others ()	7

Package FP-7S



Eff. Date	Eff. Date	Eff. Date	Eff. Date
11-Feb-1999			



Checkee	d I					
Approv			duct Spec (Technical AN75	86	Total Page Page No.	12 9
-FF						
Pin No.	Function	Adjacent Circ	uitry	Pins Description /	Signal	DC Bias (V)
1	Ripple Filter			This is the pin to conne positive terminal of a r filter capacitor.	ect the ripple	Vcc-1.5VBE
2	Input GND			Input ground pin.		0V
3	Input		400Ω 30kΩ	This is the amplifier in	iput pin.	0V
Eff. Da	te Eff. Da	ate Eff. Date	Eff. Date			

Prepared	Product Specifications	Ref No.	G - 2
Checked	(Technical Data)	Total Page	12
Approved	AN7586	Page No.	10

Pin No.	Function	Adjacent Cir	rcuitry	Pins Description / Signal	DC Bias (V)
4	Output	Pre Amp Drives		Output pin	Vcc/2
5	Output Gnd			Output ground.	0V
6	Vcc			This is the power supply pin.	Typ: 26V
7	Standby		5kΩ 5kΩ 5kΩ 3kΩ	Standby control pin. Standby Mode = 0 V Operational Mode = Vcc	
ff Da		Data Eff Data	Eff Data		
ff. Da	ate Eff.	Date Eff. Date	Eff. Date		



Application's Precautions

- (1) External heatsink is needed when used. External heatsink should be fixed to the chassis.
- (2) Fin of the IC can be connected to GND.
- (3) Please prevent "Output to V_{CC} short", "Output to GND short", "Pin Shift" in direction of Pin 7 and "Reverse Insertion" to avoid damaging the IC.
- (4) The temperature protection circuit will operate at Tj around 150°C. However, if temperature decrease, the protection circuit will automatically be deactivated and resume normal operation.

Eff. Date	Eff. Date	Eff. Date	Eff. Date
11-Feb-1999			